IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Steven J. Koester Examiner: Anh D. Mai

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TRANSISTOR HAVING STRAINED-LAYER

(Previously Amended)

Confirmation No: 7401

Commissioner of Patents and Trademarks P.O. Box 1450 Alexandria, Virginia 22313-1450

SUPPLEMENTAL AMENDMENT

Sir:

Further to applicants amendment submitted July 21, 2008 in response to the Office Action dated March 19, 2008, applicants respectfully request the Examiner to reconsider the application in view of the following corrective amendments and remarks.

 ${\bf Amendments\ to\ the\ Claims}\ {\rm are\ reflected\ in\ the\ listing\ of\ claims\ which\ begins\ on}$ page 2 of this paper.

Remarks begin on page 7 of this paper.

CERTIFICATE OF ELECTRONIC FILING

I hereby certify that this correspondence is being deposited with the United States Patent & Trademark Office via Electronic Filing through the United States Patent and Trademark Office e-business website, on July 31, 2008.

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Dated: July 31, 2008

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